

## J108 N-CHANNEL JFET



# Linear Systems replaces discontinued Siliconix J108

This n-channel JFET is optimised for low noise high performance switching. The part is particularly suitable for use in low noise audio amplifiers. The hermetically sealed TO-18 package is well suited for hi-reliability and harsh environment applications.

(See Packaging Information).

#### J108 Benefits:

- Low On Resistance
- Low insertion loss
- Low Noise

#### J108 Applications:

- Analog Switches
- Commutators
- Choppers

FEATURES					
DIRECT REPLACEMENT FOR SILICONIX J108					
LOW ON RESISTANCE	r <sub>DS(on)</sub> ≤ 8Ω				
FAST SWITCHING	t <sub>(on)</sub> ≤ 4ns				
ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)					
Maximum Temperatures					
Storage Temperature	-55°C to +150°C				
Operating Junction Temperature	-55°C to +150°C				
Maximum Power Dissipation					
Continuous Power Dissipation	350mW				
MAXIMUM CURRENT					
Gate Current (Note 1)	50mA				
MAXIMUM VOLTAGES					
Gate to Drain Voltage	V <sub>GDS</sub> = -25V				
Gate to Source Voltage	V <sub>GSS</sub> = -25V				

## J108 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
$BV_{GSS}$	Gate to Source Breakdown Voltage	-25				$I_{G} = 1\mu A$ , $V_{DS} = 0V$
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-3		-10		$V_{DS} = 5V$ , $I_{D} = 1\mu A$
V <sub>GS(F)</sub>	Gate to Source Forward Voltage		0.7		V	$I_G = 1mA$ , $V_{DS} = 0V$
I <sub>DSS</sub>	Drain to Source Saturation Current (Note 2)	80			mA	$V_{DS} = 15V, V_{GS} = 0V$
I <sub>GSS</sub>	Gate Reverse Current	-	-0.01	-3		$V_{GS} = -15V, \ V_{DS} = 0V$
I <sub>G</sub>	Gate Operating Current		-0.01		nA	$V_{DG} = 10V, I_{D} = 10mA$
I <sub>D(off)</sub>	Drain Cutoff Current		0.02	3		$V_{DS} = 5V, V_{GS} = -10V$
r <sub>DS(on)</sub>	Drain to Source On Resistance	-	-	8	Ω	$V_{GS} = 0V, V_{DS} \le 0.1V$

# J108 DYNAMIC ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

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SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	U <mark>NIT</mark> S	CONDITIONS
g <sub>fs</sub>	Forward Transconductance		17		mS	$V_{DS} = 5V$ , $I_{D} = 10 \text{mA}$ , $f = 1 \text{kHz}$
gos	Output Conductance		0.6			
r <sub>DS(on)</sub>	Drain to Source On Resistance			8	Ω	$V_{GS} = 0V$ , $I_0 = 0A$ , $f = 1kHz$
C <sub>iss</sub>	Input Capacitance		60	85		$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
C <sub>rss</sub>	Reverse Transfer Capacitance		11	15	pF	$V_{DS} = 0V$ , $V_{GS} = -10V$ , $f = 1MHz$
e <sub>n</sub>	Equivalent Noise Voltage		3.5		nV/√Hz	$V_{DS} = 5V$ , $I_{D} = 10 \text{mA}$ , $f = 1 \text{kHz}$

### J108 SWITCHING CHARACTERISTICS @ 25°C (unless otherwise noted)

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SYMBOL	CHARACTERISTIC		UNITS	CONDITIONS			
t <sub>d(on)</sub>	Turn On Time	3		V <sub>DD</sub> = 1.5V			
t <sub>r</sub>	Turn On Rise Time	1	nc	ns	V <sub>GS</sub> (H) = 0V		
t <sub>d(off)</sub>	Turn Off Time	4	113	See Switching Circuit			
t <sub>f</sub>	Turn Off Fall Time	18					

Note 1 - Absolute maximum ratings are limiting values above which J108 serviceability may be impaired. Note 2 - Pulse test: PW  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  3%

#### **J108 SWITCHING CIRCUIT PARAMETERS**

V <sub>GS(L)</sub>	-12V
$R_L$	150Ω
I <sub>D(on)</sub>	10mA

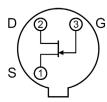
Micross Components Europe

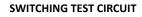
Available Packages:

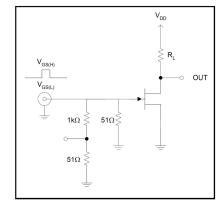
J108 in TO-18 J108 in bare die.

Please contact Micross for full package and die dimensions

#### TO-18 (Bottom View)







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